

View Online at <https://aerobasegroup.com/nsn/5961-01-357-4779>

Inclosure Material:

Glass all semiconductor device diode

Overall Length:

0.175 inches all semiconductor device diode

Terminal Length:

0.500 inches all semiconductor device diode

Overall Diameter:

0.075 inches all semiconductor device diode

Function For Which Designed:

Voltage variable capacitor

Internal Configuration:

Junction contact all semiconductor device diode

Internal Junction Configuration:

Pn all semiconductor device diode

Component Function Relationship:

Matched

Component Name And Quantity:

82 semiconductor device diode

Mounting Method:

Terminal all semiconductor device diode

Features Provided:

Hermetically sealed case and burn in

Semiconductor Material:

Silicon all semiconductor device diode

Voltage Rating In Volts Per Characteristic:

30.0 reverse voltage, instantaneous all semiconductor device diode

Current Rating Per Characteristic:

200.00 milliamperes source cutoff current preset all semiconductor device diode

Power Rating Per Characteristic:

400.0 milliwatts small-signal input power, common-collector preset all semiconductor device diode

Maximum Operating Temperature Per Measurement Point:

125.0 degrees celsius junction all semiconductor device diode

Terminal Type And Quantity:

2 uninsulated wire lead all semiconductor device diode

Shelf Life:

N/a

Unit Of Measure:

--

Demilitarization:

No

Fig:

A110a0